SMC SANGDEST MICROELECTRONICS

STF3045C Green Products

ST3045C

STB3045C

# ST3045C/STB3045C/STF3045C SCHOTTKY RECTIFIER

### **Applications:**

**Technical Data** 

Data Sheet N1311, Rev. B

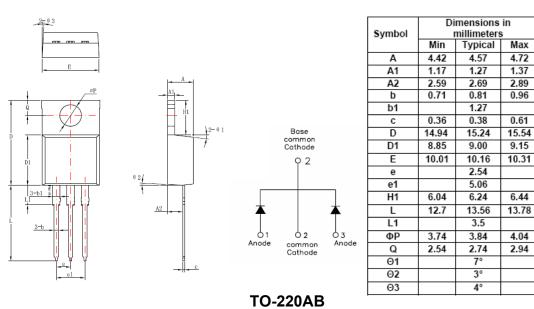
- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### Features:

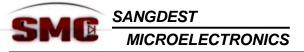
- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



### Mechanical Dimensions: In Inches / mm

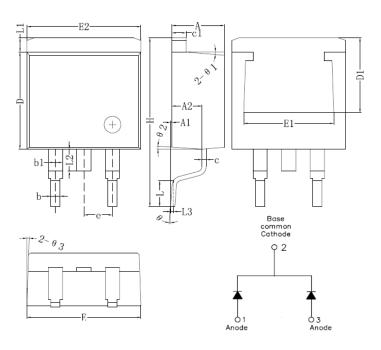


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## ST3045C STB3045C STF3045C

Technical Data Data Sheet N1311, Rev. B **Green Products** 



Symbol		Dimensions in millimeters			
•	Min.	Typical	Max.		
Α	4.55	4.70	4.85		
A1	0	0.10	0.25		
A2	2.59	2.69	2.89		
b	0.71	0.81	0.96		
b1		1.27			
С	0.36	0.38	0.61		
c1	1.17	1.27	1.37		
D	8.55	8.70	8.85		
D1	6.40				
Е	10.01	10.16	10.31		
E1	7.6				
E2	9.98	10.08	10.18		
е		2.54			
Н	14.6	15.1	15.6		
L	2.00	2.30	2.70		
L1	1.17	1.27	1.40		
L2			2.20		
L3		0.25BSC			
е	0	-	8°		
e1		5°			
e2		4°			
e3		4°			

**D<sup>2</sup>PAK** 

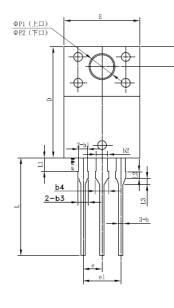


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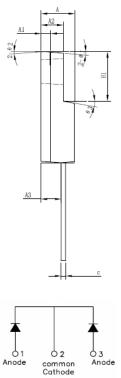
## ST3045C STB3045C STF3045C

**Green Products** 

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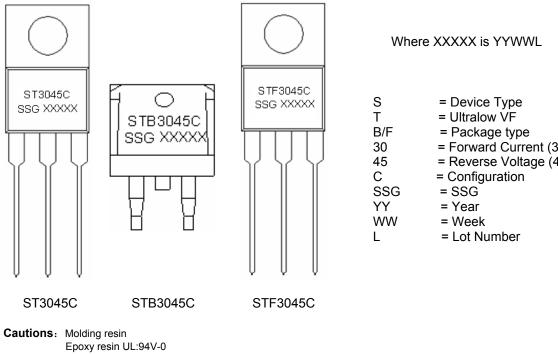
SYMBOL	MIN.	TYP.	MAX.
A	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	2.70 0.60	0.75
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
C D	0.55	0.60	0.75
D	14.80	15.00	15.20
E	9.96	10.16	10.36
е		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	2.00 1.20
L3	0.60	0.80	1.00
ΦΡ1(上口)	3.30	3.50	3.70
<b>ΦΡ2</b> (下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
Θ1		5°	
Θ2		4°	
Θ3		10°	
Θ4		5°	
Θ5		5°	

ITO-220AB

SANGDEST N **MICROELECTRONICS** 

### **Technical Data** Data Sheet N1311, Rev. B

### Marking Diagram:



### **Ordering Information:**

Device	Package	Shipping
ST3045C	TO-220AB(Pb-Free)	50pcs / tube
STB3045C	D <sup>2</sup> PAK(Pb-Free)	800pcs / reel
STF3045C	ITO-220AB(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	45	V
Average Forward Current	I <sub>F(AV)</sub>	50% duty cycle @T <sub>c</sub> =135°C rectangular wave form	30	А
Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	200	A

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S	= Device Type
Т	= Ultralow VF
B/F	= Package type
30	= Forward Current (30A)
45	= Reverse Voltage (45V)
С	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number



## ST3045C STB3045C STF3045C

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (per leg) *	$V_{\text{F1}}$	@ 7.5A, Pulse, T <sub>J</sub> = 25 °C @ 15A, Pulse, T <sub>J</sub> = 25 °C	0.44 0.49	0.53 0.57	V
	V <sub>F2</sub>	@ 7.5A, Pulse, T <sub>J</sub> = 125 °C @ 15A, Pulse, T <sub>J</sub> = 125 °C	0.33 0.39	0.42 0.48	V
Reverse Current at DC condition (per leg)	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.21	2.0	mA
Reverse Current (per leg) *	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 125 °C	120	150	mA
Junction Capacitance (per leg)	CT	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	868	-	pF

\* Pulse Width < 300µs, Duty Cycle <2%

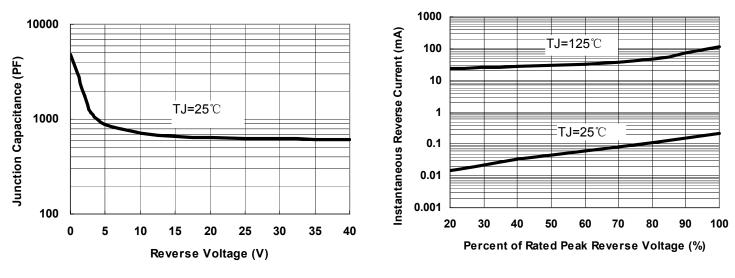
### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	С°
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	$R_{ ext{ heta}JC}$	DC operation	1.6	°C/W
Approximate Weight	wt	-	2/1.85/2	g
Case Style	TO-220AB/D <sup>2</sup> PAK/ITO-220AB			



## ST3045C STB3045C STF3045C

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**Fig.2-Typical Reverse Characteristics** 

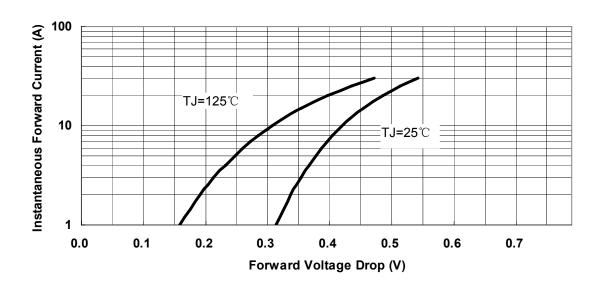
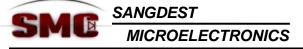


Fig.3-Typical Instantaneous Forward Voltage Characteristics



#### Technical Data Data Sheet N1311, Rev. B

STF3045C

ST3045C

STB3045C

## Green Products

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